

Effect of topology on the transport properties of two interacting dots

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Abstract. The transport properties of a system of two interacting dots, one of them directly connected to the leads constituting a side-coupled configuration (SCD), are studied in the weak and strong tunnel-coupling limits. The conductance behavior of the SCD structure has new and richer physics than the better-studied system of two dots aligned with the leads (ACD). In the weak coupling regime and in the case of one electron per dot, the ACD configuration gives rise to two mostly independent Kondo states. In the SCD topology, the inserted dot is in a Kondo state while the side-connected one presents Coulomb blockade properties. Moreover, the dot spins change their behavior, from an antiferromagnetic coupling to a ferromagnetic correlation, as a consequence of the interaction with the conduction electrons. The system is governed by the Kondo effect related to the dot that is embedded into the leads. The role of the side-connected dot is to introduce, when at resonance, a new path for the electrons to go through giving rise to the interferences responsible for the suppression of the conductance. These results depend on the values of the intra-dot Coulomb interactions. In the case where the many-body interaction is restricted to the side-connected dot, its Kondo correlation is responsible for the scattering of the conduction electrons giving rise to the conductance suppression.

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1 Introduction

In the last years interest in double-quantum-dot systems has been renewed [1] since they have been proposed as basic building blocks for quantum computers [2]. The strength of the interaction between the two quantum dots determines the character of the electronic states and the nature of the transport through them. In the limit of weak tunneling interaction the electrons are localized on the individual dots while in the strong limit the delocalized electronic charge is no longer quantized. The transport properties depend also on the topology of the double-dot system. For the case of the two dots aligned with the leads (ACD), in the weak coupling limit the interaction of each individual dot with the conduction electrons of the nearby lead gives rise to the Kondo phenomenon. In the opposite limit, the strong inter-dot tunneling interaction together with the intra-dot Coulomb repulsion result in an anti-parallel correlation of the two dot spins that quenches the Kondo effect. As the tunneling interaction is increased the dot system goes continuously from the Kondo regime to an antiferromagnetic state. The interplay between the interactions that give rise either to the Kondo

effect or to the dot-dot antiferromagnetic correlation is reflected on the conductance of the system [3,4]. Another system of two-interacting dots in the side-connected configuration (SCD) has special interest since it permits, in principle, the control of the current along the leads by changing the state of charge of the side-connected dot. The conductance of this system, in the particular case where the Coulomb interaction is restricted to the side-connected dot, has already been investigated in two cases: a) considering the charge of the side-connected dot fixed at one electron and neglecting charge fluctuations so that the dot could be treated as an $S = 1/2$ spin [5]; b) letting its charge to be varied by the application of a gate potential [6]. These studies conclude that, at low temperature, the linear-response conductance in the leads is suppressed due to the Kondo scattering of spin $S = 1/2$ of the side-connected dot. However, new and very interesting physics appears when both dots have many-body interactions and both charges can be varied. Manipulating the dot gate potentials, the system can go through a ground state transition modifying its properties, particularly the conductance and the interdot and the dot-conduction-electron spin correlations.

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In this paper we address this new physics by studying the conductance for all states of charge of the dots and various regimes of the system, in the weak and strong inter-dot tunneling coupling. We analyze the differences between the SCD and the ACD configuration. We find that the transport properties for these two topologies are quite different when the inter-dot tunneling coupling is weak. In the SCD configuration, if there is one electron at each dot their spins are ferromagnetic correlated constituting a triplet state, while the dot inserted into the leads forms a conduction electron Kondo cloud in its neighborhood and the side-connected one stays in the Coulomb blockade regime.

2 Method

An Anderson two-impurity first neighbor tight binding Hamiltonian represents the system schematically depicted in Figure 1. The total Hamiltonian reads,

$$H = \sum_{r=\alpha,\beta} \left(V_r + \frac{U_r}{2} n_{r\bar{\sigma}} \right) n_{r\sigma} + t_D \sum_{\sigma} (c_{\alpha\sigma}^{\dagger} c_{\beta\sigma} + \text{c.c.}) + t' \sum_{\sigma} [(c_{\alpha\sigma}^{\dagger} c_{1\sigma} + c_{\alpha\sigma}^{\dagger} c_{\bar{1}\sigma} + \text{c.c.})] + t \sum_{i,j,\sigma} c_{i\sigma}^{\dagger} c_{j\sigma} \quad (1)$$

where dot α , inserted into the leads, interacts with its nearest neighbor sites 1 and $\bar{1}$ through the hopping matrix element t' . The interactions between the dots α and β and among the lead sites are represented by the hopping matrix elements t_D and t , respectively. The parameters V_r and U_r represent, respectively, the gate potential and the intra-dot Coulomb interaction in each dot. To describe the very low temperature properties we calculate the one particle Green functions $G_{\alpha,\beta}$ at the dots. Part of the system, consisting of a cluster that includes the two dots and some lead sites, is exactly solved and then embedded into the rest of the contacts. The Green functions are made to satisfy a Dyson equation $\hat{G} = \hat{g} + \hat{g}\hat{T}\hat{G}$ where \hat{g} is the cluster Green function matrix and \hat{T} is the matrix of the coupling Hamiltonian between the cluster and the rest of the system. The undressed Green function \hat{g} is calculated using the cluster ground state obtained by the Lanczos method [7]. In order to guarantee consistency the charge of the dressed and undressed cluster is imposed to be the same [8]. We calculate \hat{g} as a combination of the Green function of n and $n+1$ electrons with weight $1-p$ and p , $\hat{g} = (1-p)\hat{g}_n + p\hat{g}_{n+1}$. The charge of the undressed cluster is $q_c = (1-p)n + p(n+1)$. The charge of the cluster when linked to the leads can be expressed as $Q_c = 2 \int_{-\infty}^{\epsilon_F} \sum_i \text{Im} G_{ii}(\omega) d\omega$, where i runs over all the cluster sites. This equation plus the condition $q_c = Q_c$ constitute a system of two equations which requires a self-consistent solution to obtain p and n . Using the Keldysh formalism [9] the conductance can be written as

$$G = \frac{e^2 t^2}{h} |G_{\alpha,\alpha}|^2 [\rho(\epsilon_F)]^2 \quad (2)$$

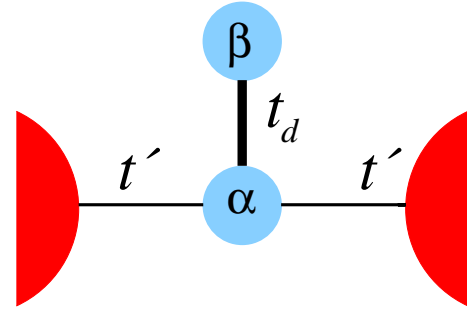


Fig. 1. Two interacting dots in the side-connected configuration.

where $G_{\alpha,\alpha}$ is the Green function at dot α while $\rho(\epsilon_F)$ is the density of states at the Fermi level at the first neighbors of dot α , when disconnected from it. This approximation has shown to be very accurate, almost numerically exact, when the cluster is of the size of the Kondo cloud $h v_F / T_K$, where v_F is the Fermi velocity, although it gives qualitatively reliable results even for shorter clusters. Moreover, the procedure satisfies the Luttinger-Ward identity that ensures the fulfillment of the Friedel sum-rule and of the Fermi liquid properties.

We calculate the conductance of the system in the weak and strong inter-dot coupling limits as the gate potentials applied to the dots are changed. The density of states, the charge inside the dots and the various spin-spin correlation functions are also calculated in order to characterize the state of the system.

3 Results

All energies are in units of the bandwidth W and the Fermi level is chosen to be $\epsilon_F = 0$. The other parameter values are $U_\alpha = U_\beta = 0.5$, and $\Gamma = t'^2 / W = 0.015$. Let us first analyze the weak tunneling coupling case, where we take $t_D = 0.15$. A general view of the conductance is presented in Figure 2 for the whole range of energy of the states localized at the dots, V_α and V_β . The conductance presents quite different characteristics depending upon the localization in the two-gate potential parameter space. In order to study these phenomena we obtain the conductance modifying the dot gate potentials in three different ways. When V_α is changed while maintaining constant V_β (along an horizontal line in the figure), the conductance presents only one peak. If, on the contrary, V_α is maintained at a fixed value in the range $-0.5 < V_\alpha < 0$, while V_β is varied (along a vertical line in the figure), the conductance is almost constant except around two values of V_β where it cancels out. This reflects the asymmetry of the two dots in the topology we are studying. On the other hand, if both dot energies are simultaneously varied, for example, along the diagonal $V_\alpha = V_\beta$ as shown in the figure, the conductance possesses three peaks. In what follows we discuss these cases in more detail.

The conductance, dot charges and spin correlations for the case where the side-connected dot local energy V_β is

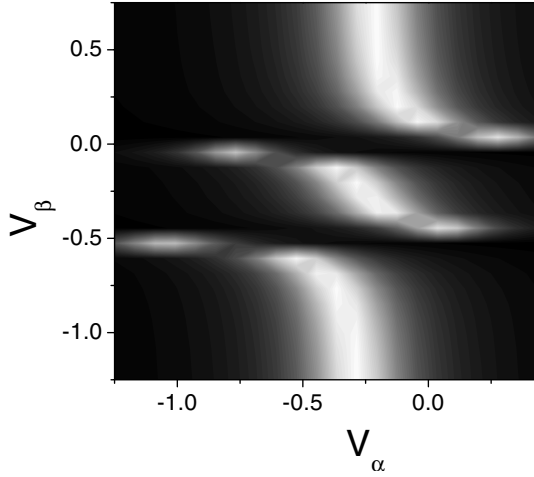


Fig. 2. Conductance (white, maximum; black, minimum) as a function of the gate potential V_α at the aligned dot and V_β at the side-connected dot. Weak coupling limit.

fixed, are presented in Figure 3 as a function of the energy V_α . We consider two situations: $V_\beta = -0.25$ when dot β has just one electron and $V_\beta = -1.0$ when it has two. In both cases the conductance and the dot α charge and spin correlation with the conduction electrons are similar. In Figure 3 we show only the results for the case $V_\beta = -0.25$. The conductance shows one peak with width of the order of U_α in the region $-0.5 < V_\alpha < 0$, where the charge at dot α grows continuously from zero to two, and the spin-spin correlation between dot α and conduction electrons, $\langle S_\alpha, S_c \rangle$, is negative. These results characterize a Kondo state related to dot α . The total spin of the two dots, S_T , and the spin correlation between dot β and conduction electrons, $\langle S_\beta, S_c \rangle$, differ for the two situations as expected, since dot β with two electrons has no spin, what is consistent with the values $S_T = 0.35$ and $\langle S_\beta, S_c \rangle = 0$ we found. For the case where each dot has just one electron we obtain $S_T = 0.65$ and $\langle S_\beta, S_c \rangle < 0$, indicating a ferromagnetic dot-dot correlation and an anti-parallel alignment of dot β and the conduction electron spins.

In order to characterize the many-body state of the dots we represent in the inset of Figure 3 the density of states (DOS) projected on each dot, at the electron-hole symmetry condition $V_\alpha = V_\beta = -0.25$. The DOS at dot α presents a resonance that is pinned at the Fermi level as V_α is changed, confirming that this dot has a Kondo resonance. However, the DOS at dot β is zero at the Fermi level and has two peaks separated by U_β , indicating that dot β is in the Coulomb blockade regime.

It is well known that the spins of two sites with large intra-Coulomb repulsion U interacting through an intersite matrix element t_D are coupled by an antiferromagnetic interaction of the order of t_D^2/U . If the two dots we are analyzing were to have a dominant antiferromagnetic spin interaction the system would not have a net spin to couple Kondo-like with the conduction electrons. We conclude that in the weak coupling limit the system reduces its energy by coupling the spin of the embedded dot in a Kondo-like manner and by transforming the inter-dot an-

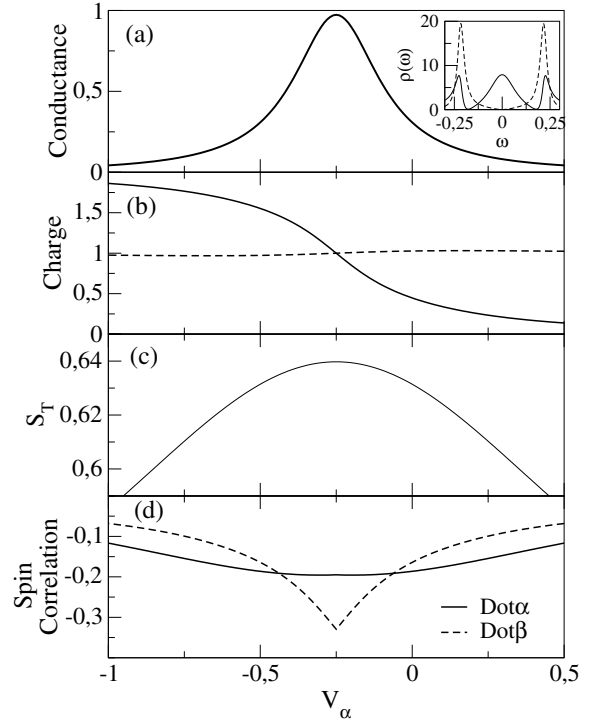


Fig. 3. Weak-coupling results for $V_\beta = -0.25$, as a function of V_α . (a) Conductance (in units of e^2/h), (b) charge (in units of e) at dot α (continuous line) and dot β (dashed line), (c) total spin and (d) spin correlation $\langle S_\alpha, S_c \rangle$ (continuous line) and $\langle S_\beta, S_c \rangle$ (dashed line). The inset shows the DOS at dot α (continuous line) and dot β (dashed line), for $V_\alpha = V_\beta = -0.25$.

tiferromagnetic spin-spin correlation into a renormalized ferromagnetic interaction. For this to occur the energy gained by the Kondo ground state, of the order of the Kondo temperature, T_K , has to be greater than the energy lost due to the ferromagnetic coupling between the dots. T_K has to satisfy the relation $T_K > t_D^2/U$. This can be clarified by solving a three site problem, representing the conduction electrons and the interacting dots, in a topological disposition such that only one of the dots interacts with the conducting site through t' . The dot-conduction electron interaction and the dot-dot interaction t_D break in a different manner the degeneracy of the $S = 1$ and $S = 0$ spin states of the two dots. These states represent the ferromagnetic and antiferromagnetic situation, respectively. While the energy of the $S = 1$ state is renormalized by a value of the order of the Kondo temperature of a localized two site system [10], given by $2t'^2/V_\alpha$, the renormalization energy of the $S = 0$ state is of the order of t_D^2/U corresponding to the inter-dot antiferromagnetic coupling. The interplay of these two quantities determines the ground state of the system. As a conclusion, in the regime we are analyzing the spins of dots α and β are parallel-aligned giving rise to a total spin greater than $1/2$.

Since dot α forms a Kondo state its spin is anti-parallel to the conduction electron spins, and so does the spin of dot β , even though dot β is not in the Kondo regime. In

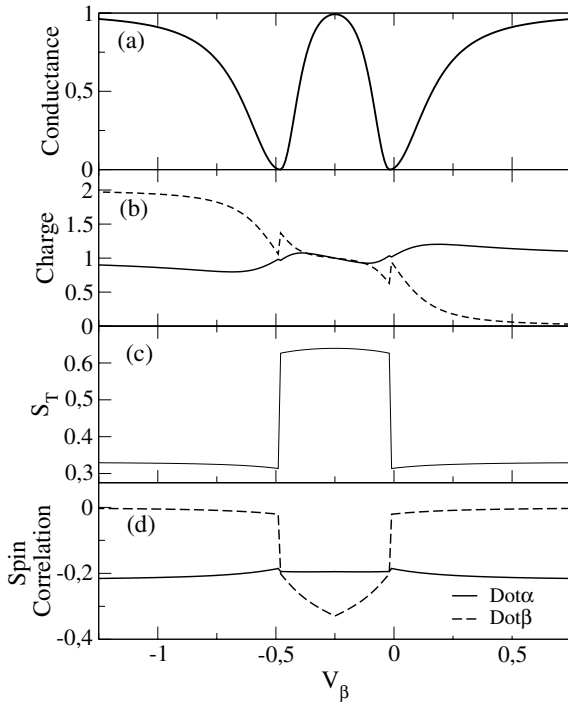


Fig. 4. Weak-coupling results for $V_\alpha = -0.25$, as a function of V_β . (a) Conductance (in units of e^2/h), (b) charge (in units of e) at dot α (continuous line) and dot β (dashed line), (c) total spin and (d) spin correlation $\langle S_\alpha, S_c \rangle$ (continuous line) and $\langle S_\beta, S_c \rangle$ (dashed line).

spite of having a localized spin, when out of resonance the side-connected dot plays no role in the conductance of the system that is governed uniquely by the Kondo effect of the inserted dot.

The results obtained when the role played by the gate potentials is interchanged, V_β is varied while maintaining $V_\alpha = -0.25$, are shown in Figure 4. Since dot α has a constant number of electrons equal to one, it is in the Kondo regime for any value of V_β . However the conductance is not constant but is suppressed at two values of V_β . This happens around $V_\beta = 0$ and $V_\beta = -U_\beta$, when the side-connected dot levels cross the Fermi energy, adding a new path for the electrons to go through, resulting in a Fano interference. As one electron enters into dot β , at $V_\beta = 0$, the total spin of the dots increases from $S_T = 0.35$ to $S_T = 0.64$ and maintains this value up to the entrance of the second electron at $V_\beta = -U_\beta = -0.5$. In this same region of gate potential the spin correlation $\langle S_\beta, S_c \rangle$ results to be negative, in agreement with the interpretation given before that the two dot spins are parallel aligned. Except for the discontinuities, the charge at dot β is maintained about constant over the Coulomb blockade region, as expected.

The case where both dot energies are simultaneously changed is depicted in Figure 5, for $V_\alpha = V_\beta$. The conductance shows three peaks and cancels out at two values of the gate potential due to the same interference phenomenon as discussed just before. Although dot α is in the Kondo regime the conductance has zeros due to de-

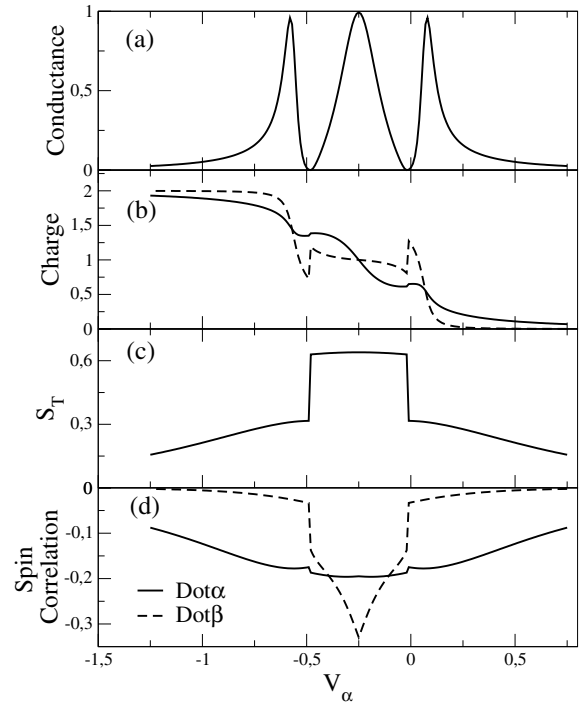


Fig. 5. Weak-coupling results as a function of gate potential for $V_\alpha = V_\beta$. (a) Conductance (in units of e^2/h), (b) charge (in units of e) at dot α (continuous line) and dot β (dashed line), (c) total spin and (d) spin correlation $\langle S_\alpha, S_c \rangle$ (continuous line) and $\langle S_\beta, S_c \rangle$ (dashed line).

structive interference between two electron paths. Charge enters continuously into dot α , as expected for a Kondo state, and abruptly at dot β , where it remains constant and equal to one for the whole range of gate potential, reflecting the Coulomb blockade regime of the dot. The behavior of the total spin and the spin-spin correlations as a function of gate potential is similar to the one presented in Figure 3.

The discontinuities present in the charge of dot β , the total spin and the spin correlation, seen in Figures 4 and 5 for two values of the gate potential, are due to a ground state crossing that results in an abrupt change of the properties of the system. These two ground states have different spatial parity reflecting the inverse symmetry that the system possesses. The discontinuity in the physical magnitudes acquires a cross-over behavior when this symmetry is broken. This can be verified by simply modifying one of the coupling matrix elements of the embedded dot.

We consider now the strong coupling limit by taking the inter-dot tunneling interaction $t_D = 0.9$. The conductance, dot charges and spin correlation as a function of the gate potentials, for the case $V_\alpha = V_\beta$, are depicted in Figure 6. In this limit, $t_D > t'$, the two dots have an effective anti-ferromagnetic coupling that aligns their spins anti-parallel as discussed above, destroying the Kondo effect. The results are similar to the ones obtained for the ACD configuration. The similarity comes from the fact that, in this limit, the two dots act as an entity so that the way each dot is connected to the leads is not relevant.

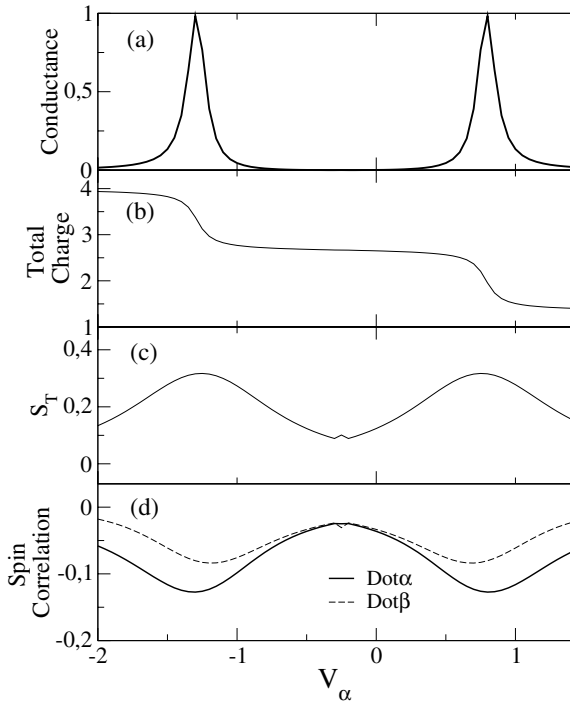


Fig. 6. Strong-coupling results as a function of gate potential for $V_\alpha = V_\beta$. (a) Conductance (in units of e^2/h), (b) total charge (in units of e), (c) total spin and (d) spin correlation $\langle S_\alpha, S_c \rangle$ (continuous line) and $\langle S_\beta, S_c \rangle$ (dashed line).

4 Summary

In conclusion, in the weak inter-dot tunneling regime the transport properties of a system of two interacting dots connected to leads have quite different features according to its topology. In the SCD configuration studied here, when the Kondo temperature is greater than the antiferromagnetic interdot spin interaction, the spins are ferromagnetic correlated due to the interaction of one of them with the conducting electrons. In this case the dot embedded into the leads forms a Kondo state with the conduction electrons while the side-connected dot is in the Coulomb blockade regime. The conductance is governed by the Kondo effect and shows three peaks as both gate potentials are varied. The suppression is due to a Fano interference of the electrons, whenever the Coulomb blockade peaks of the

side-connected dot cross the Fermi level. On the other hand, in the ACD configuration the dots are independently Kondo correlated to the conduction electrons of the leads to which they are connected. The conductance shows a broad peak due to the Kondo resonance at both dots [3,4].

In the strong-coupling limit the behavior of the conductance is the same for the two topologies. The similarity comes from the fact that in this limit the two dots act as a molecule so that the way each dot is connected to the leads is not relevant.

Therefore, if both dots have many-body interactions the side-connected dot does not give any Kondo contribution to the transport properties of this system. This result is quite different from the one obtained in the case the many-body interaction is restricted to the side-connected dot [5], where it is just the Kondo effect of this dot that scatters the conduction electrons giving rise to the conductance cancellation.

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